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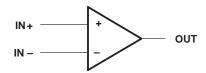
- μA741 Operating Characteristics
- Low Supply Current Drain . . . 0.6 mA Typ (per amplifier)
- Low Input Offset Voltage
- Low Input Offset Current
- Class AB Output Stage
- Input/Output Overload Protection
- Designed to Be Interchangeable With National LM148, LM248, and LM348

description

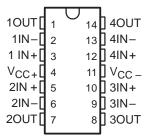
The LM148, LM248, and LM348 are quadruple, independent, high-gain, internally compensated operational amplifiers designed to have operating characteristics similar to the μ A741. These amplifiers exhibit low supply current drain, and input bias and offset currents that are much less than those of the μ A741.

The LM148 is characterized for operation over the full military temperature range of -55° C to 125°C, the LM248 is characterized for operation from -25° C to 85°C, and the LM348 is characterized for operation from 0°C to 70°C.

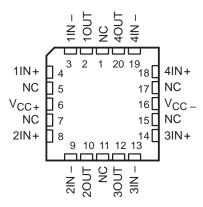
symbol (each amplifier)



LM148...J PACKAGE LM248, LM348...D, N, OR PW PACKAGE (TOP VIEW)



LM148...FK PACKAGE (TOP VIEW)



NC - No internal connection

AVAILABLE OPTIONS

		PACKAGE							
TA	V _{IO} max AT 25°C	SMALL OUTLINE (D)	CHIP CARRIER (FK)	CERAMIC DIP (J)	PLASTIC DIP (N)	TSSOP (PW)			
0°C to 70°C	6 mV	LM348D	_		LM348N	LM348PW			
-25°C to 85°C	6 mV	LM248D	_		LM248N	_			
-55°C to 125°C	5 mV	_	LM148FK	LM148J	_	_			

The D package is available taped and reeled. Add the suffix R to the device type (e.g., LM348DR).



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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

		LM148	LM248	LM348	UNIT	
Supply voltage, V _{CC+} (see Note 1)	ge, V _{CC+} (see Note 1) 22 18 18					
Supply voltage, V _{CC} (see Note 1)	-22	-18	-18	V		
Differential input voltage, V _{ID} (see Note 2)		44	36	36	V	
Input voltage, V _I (either input, see Notes 1 and 3)		±22	±18	±18	V	
Duration of output short circuit (see Note 4)	unlimited	unlimited	unlimited			
Continuous total power dissipation	See Dissipation Rating Table					
Operating free-air temperature range, TA		-55 to 125	-25 to 85	0 to 70	°C	
Storage temperature range		-65 to 150 -65 to 150 -65 to 150 °				
Case temperature for 60 seconds	FK package	260			°C	
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds	J package	300			°C	
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	D, N, or PW package		260	260	°C	

- NOTES: 1. All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-}.
 - 2. Differential voltages are at IN+ with respect to IN-.
 - 3. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or the value specified in the table, whichever is less.
 - 4. The output may be shorted to ground or either power supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded.

DISSIPATION RATING TABLE

PACKAGE	$T_{\mbox{A}} \le 25^{\circ}\mbox{C}$ POWER RATING	DERATING FACTOR	DERATE ABOVE T _A	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING	T _A = 125°C POWER RATING
D	900 mW	7.6 mW/°C	32°C	611 mW	497 mW	N/A
FK	900 mW	11.0 mW/°C	68°C	878 mW	713 mW	273 mW
J	900 mW	11.0 mW/°C	68°C	878 mW	713 mW	273 mW
N	900 mW	9.2 mW/°C	52°C	734 mW	596 mW	N/A
PW	700 mW	5.6 mW/°C	N/A	448 mW	N/A	N/A

recommended operating conditions

	MIN	MAX	UNIT
Supply voltage, V _{CC+}	4	18	V
Supply voltage, V _{CC} _	-4	-18	V

PARAMETER		_	FOT CONDITIO	augt	LM148			LM248			LM348			UNIT	
	FARAMETER	TEST CONDITIONS†		MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT		
\/10	Input offset voltage	VO = 0		25°C		1	5		1 6			1	6	mV	
V _{IO} Input offset voltage		VO = 0		Full range			6			7.5			7.5		
10	Input offset current	VO = 0		25°C		4	25		4	50		4	50	nA	
10	input onset current	VO = 0		Full range			75			125			100	11/4	
IB	Input bias current	VO = 0		25°C		30	100		30	200		30	200	nA	
ııB	input bias current	VO = 0		Full range			325			500			400	11/4	
VICR	Common-mode input voltage range			Full range	±12			±12			±12			V	
		R _L = 10 ks	2	25°C	±12	±13		±12	±13		±12	±13			
VOM	Maximum peak output voltage	$R_L \geq 10 \; k\Omega$		Full range	±12			±12			±12			v	
VOIM	swing	$R_L = 2 k\Omega$		25°C	±10	±12		±10	±12		±10	±12			
		$R_L \geq 2 \; k\Omega$		Full range	±10			±10			±10				
AVD	Large-signal differential voltage	$V_{O} = \pm 10 \text{ V},$		25°C	50	160		25	160		25	160		V/mV	
AVD	amplification	$R_L = \ge 2 \text{ k}\Omega$	2	Full range	25			15			15			V/IIIV	
rį	Input resistance‡			25°C	0.8	2.5		0.8	2.5		0.8	2.5		MΩ	
B ₁	Unity-gain bandwidth	$A_{VD} = 1$		25°C		1			1			1		MHz	
φm	Phase margin	$A_{VD} = 1$		25°C		60°			60°			60°			
CMRR	Common-mode rejection ratio	V _{IC} = V _{ICR} min,		25°C	70	90		70	90		70	90		dB	
CIVILLIX	Common-mode rejection ratio	VO = 0		Full range	70			70			70			uВ	
kovo	Supply-voltage rejection ratio	$V_{CC+} = \pm 9 \text{ V to } \pm 15$	9 V to ± 15 V,	25°C	77	96		77	96		77	96		dB	
ksvr	$(\Delta V_{CC\pm}/\Delta V_{IO})$			Full range	77			77			77			uB	
los	Short-circuit output current			25°C		±25	, and the second		±25	, and the second		±25		mA	
loo	Supply current (four amplifiers)	No load	V _O = 0	25°C					2.4	4.5		2.4	4.5	mA	
lcc	Supply current (rour amplifiers)	V _O = V _{OM}		25-0		2.4	3.6			, and the second				IIIA	
V _{O1} /V _{O2}	Crosstalk attenuation	f = 1 Hz to	20 kHz	25°C		120			120			120		dB	

[†] All characteristics are measured under open-loop conditions with zero common-mode input voltage unless otherwise specified. Full range for T_A is -55°C to 125°C for LM148, -25°C to 85°C for LM248, and 0°C to 70°C for LM348.

† This parameter is not production tested.

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operating characteristics, $V_{CC\pm}$ = ± 15 V, T_A = $25^{\circ}C$

PARAMETER		Т	EST CONDITIO	MIN	TYP	MAX	UNIT	
SR	Slew rate at unity gain	$R_L = 2 k\Omega$,	$C_L = 100 pF$,	See Figure 1		0.5		V/μs

PARAMETER MEASUREMENT INFORMATION

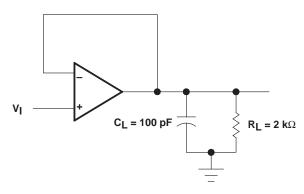


Figure 1. Unity-Gain Amplifier

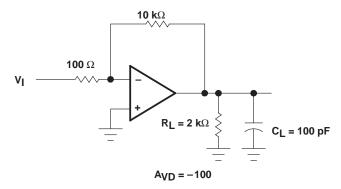


Figure 2. Inverting Amplifier

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